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Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-033-5074

New Online at https://aeiobasegioup.com/hsi//3901-01-035-3074	
Inclosure Material:	
Metal	
Overall Length:	
Between 0.170 inches and 0.210 inches	
Terminal Length:	
Between 0.500 inches and 0.750 inches	
Overall Diameter:	
Between 0.209 inches and 0.230 inches	
Internal Configuration:	
Junction contact	
Joint Electronic Device Engineering Council/jedec/case Outline Designation	n:
Го-18	
Electrode Internally-electrically Connected To Case:	
Anode	
Mounting Method:	
Terminal	
Terminal Circle Diameter:	
0.100 inches	
Features Provided:	
Hermetically sealed case	
Semiconductor Material:	
Silicon	
Current Rating Per Characteristic:	
175.00 milliamperes forward current, average absolute	
Maximum Operating Tempurature Per Measurement Point:	
150.0 degrees celsius junction	
Special Features:	
Junction pattern arrangement: pnpn	
Test Data Document:	
31349-mil-s-19500 specification (includes engineering type bulletins, brochures,	etc., that reflect specification type data in specification
ormat; excludes commercial catalogs, industry directories, and similar trade pu	ublications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown	as "typical", "average", "", etc.).
Terminal Type And Quantity:	
3 uninsulated wire lead	
Specification Data:	
81349-mil-s-19500/419 government specification	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
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